

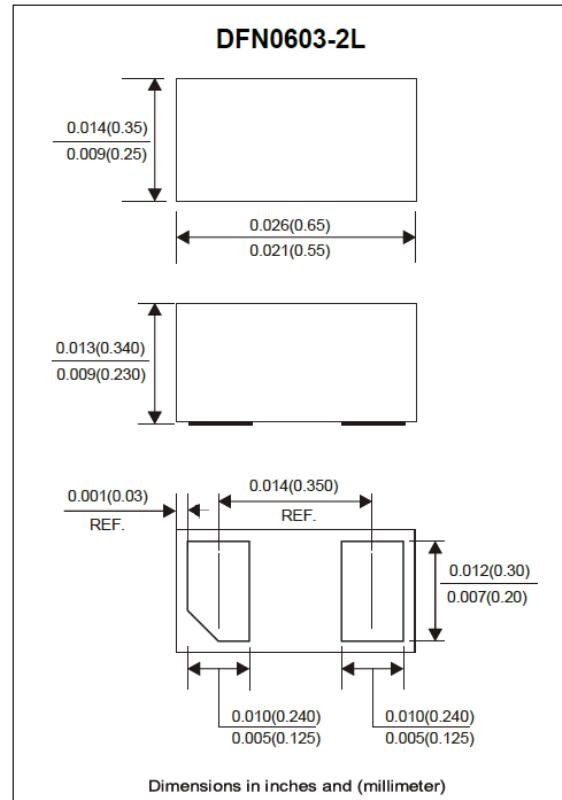
1-Line Bi-directional TVS Diode

Features

- IEC 61000-4-2 (ESD) $\pm 30\text{kV}$ (air), $\pm 30\text{kV}$ (contact)
- IEC 61000-4-4 (EFT) 40A (5/50 ns)
- IEC 61000-4-5 (Lightning) 11A (8/20 μs)
- Ultra small package: 0.6x0.3x0.3mm
- Low capacitance
- Low leakage current
- Operating voltage: 5.5V
- Low clamping voltage
- Protects one data or power line

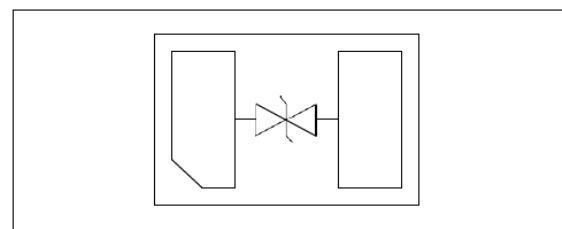
Applications

- Cellular Handsets and Accessories
- Computers and Peripherals
- Communication Systems
- Digital Cameras
- Audio Players

**Mechanical Characteristics**

- Package: DFN0603-2L (0.6x0.3x0.3mm)
- Case Material: "Green" Molding Compound.
- Moisture Sensitivity: Level 3 per J-STD-020
- Material : Halogen free , RoHS compliant

Circuit Diagram

**Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$ Unless otherwise noted)**

Parameter	Symbol	Value	Unit
Peak Pulse Power ($tp = 8/20\mu\text{s}$)	P_{PP}	165	W
Peak Pulse Current ($tp = 8/20\mu\text{s}$)	I_{PP}	11	A
ESD per IEC 61000-4-2 (Air)	V_{ESD}	± 30	KV
ESD per IEC 61000-4-2 (Contact)		± 30	KV
Operating Temperature Range	T_J	-55 to + 125	$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-55 to + 150	$^\circ\text{C}$

Electrical Parameters ($T_A = 25^\circ\text{C}$ Unless otherwise noted)

Symbol	Parameter	
I_{PP}	Reverse Peak Pulse Current	
V_C	Clamping Voltage @ I_{PP}	
V_{RWM}	Reverse Stand-Off Voltage	
I_R	Reverse Leakage Current @ V_{RWM}	
V_{BR}	Breakdown Voltage @ I_T	
I_T	Test Current	

The graph illustrates the relationship between current (I) and voltage (V) for the diode. The vertical axis represents current (I) and the horizontal axis represents voltage (V). The curve shows a low-current region followed by a sharp increase in current, characteristic of a Zener diode. Key points are labeled: V_C (Clamping Voltage), V_{BR} (Breakdown Voltage), V_{RWM} (Reverse Working Voltage), I_T (Test Current), I_R (Reverse Leakage Current), and I_{PP} (Reverse Peak Pulse Current).

Electrical Characteristics ($T_A = 25^\circ\text{C}$ Unless otherwise noted)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Reverse Working Voltage	V_{RWM}				5.5	V
Reverse breakdown Voltage	V_{BR}	$I_T = 1\text{mA}$	6			V
Reverse leakage current	I_R	$V_{RWM} = 5.5\text{V}$			50	nA
Clamping Voltage	V_C	$I_{PP} = 1\text{A}, t_p = 8/20\mu\text{s}$		8	10	V
Clamping Voltage	V_C	$I_{PP} = 11\text{A}, t_p = 8/20\mu\text{s}$		13	15	V
Junction capacitance	C_J	$V_R = 0\text{V}, f = 1\text{MHz}$		10	15	pF

Typical Performance Characteristics ($T_A = 25^\circ\text{C}$ Unless otherwise noted)

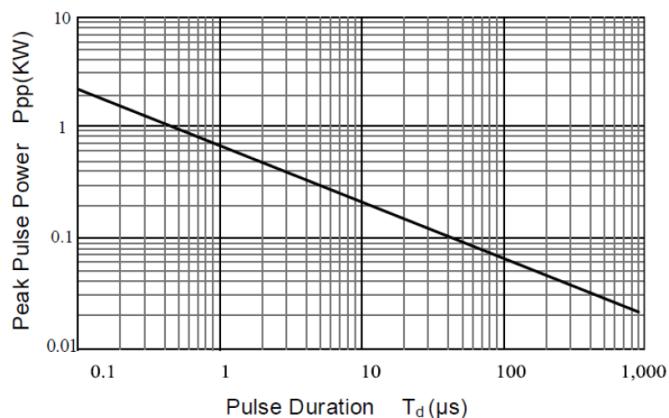


Fig 1. Peak Pulse Power vs. Pulse Time

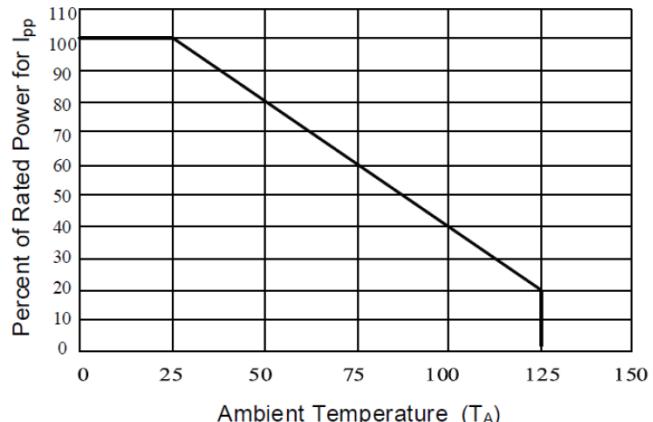


Fig 2. Power Derating Curve

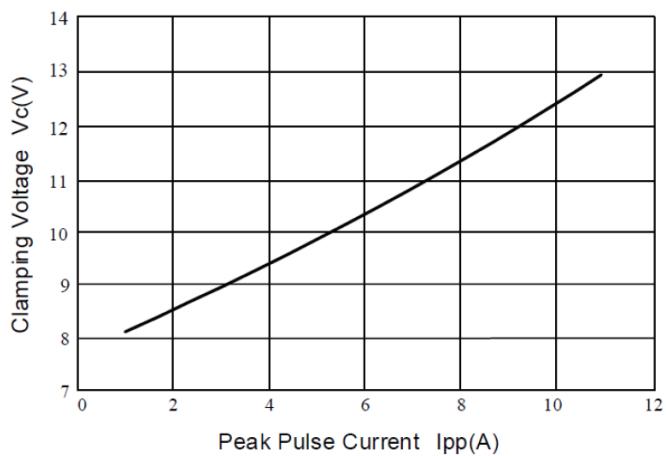


Fig 3. Clamping Voltage vs. Peak Pulse Current

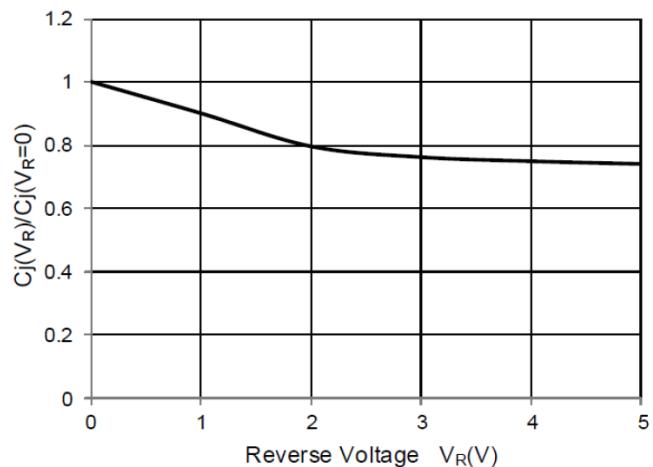


Fig 4. Junction Capacitance vs. Reverse Voltage

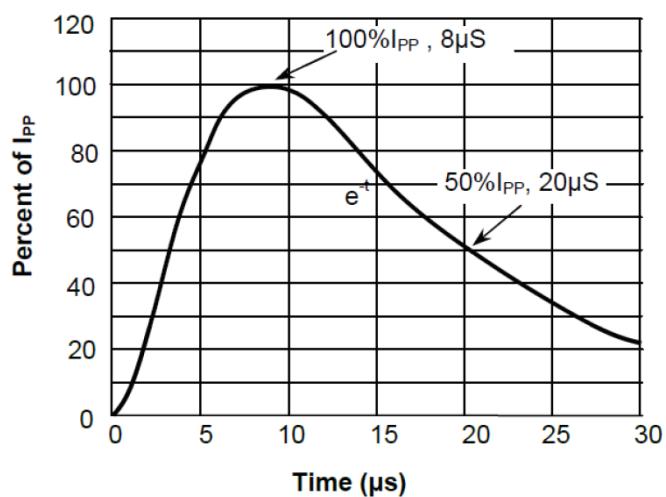


Fig 5. 8 X 20 μs Pulse Waveform

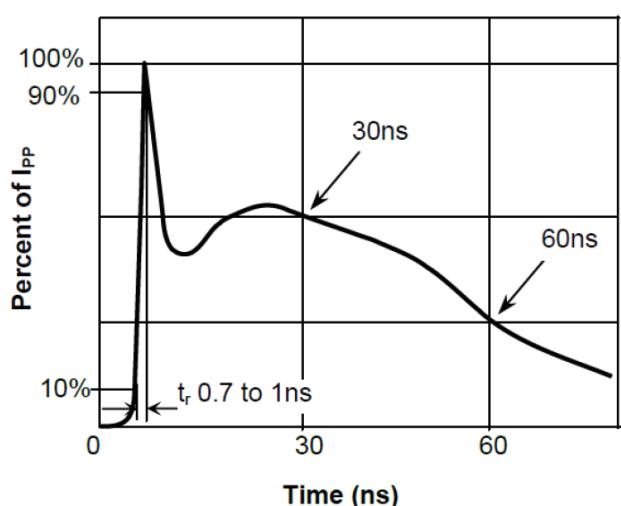


Fig 6. ESD(IEC61000-4-2) Pulse Waveform

Suggested PAD Layout

Symbol	DFN0603-2L	
	(mm)	(inch)
A	0.16	0.006
B	0.24	0.009
C	0.34	0.013
D	0.40	0.016
E	0.64	0.025

Marking Code

Part Number	Marking Code
SLN050B1FS-D6	Z4

Tape and Reel Specification

Symbol	Millimeters
A	0.37±0.03
B	0.67±0.03
C	0.35±0.03
d	1.50+0.10/-0.00
E	1.75±0.10
F	3.50±0.05
P	2.00±0.05
P0	4.00±0.10
P1	2.00±0.05
T	0.20±0.02
W	8.00+0.30/-0.10

Ordering information

Part Number	Package	Base qty	Reel Size	Delivery mode
		(pcs)	(inch)	
SLN050B1FS-D6	DFN0603-2L	10,000	7	Tape and reel